

**BTA24 / BTB24
Triac Series**
TO-220

Absolute maximum ratings ($T_{amb}=25^{\circ}\text{C}$)

Parameter		Symbol	Value	Unit	Test condition
peak repetitive off-stage voltage	BTA/BTB-600	V _{DRM} , V _{RRM}	600	V	I _D =0.1mA, I _R =0.1mA
peak repetitive off-stage voltage	BTA/BTB-800	V _{DRM} , V _{RRM}	800	V	I _D =0.1mA, I _R =0.1mA
on-state RMS current		I _T (RMS)	25	A	all conduction angles
NON repetitive surge peak on-state current		I _{TSM}	250	A	Tp=10ms, T _j =25 °C
critical rate of rise on-state current		di/dt	50	A/μs	I _{TM} =20A, I _G =50mA
peak gate current		I _{GM}	4	A	tp=20μs
average gate power dissipation		P _G (AV)	1	W	
storage temperature range		Tstg	-40 to +150	°C	
operating junction temperature range		Tj	125	°C	

Electrical characteristics ($T_j=25^{\circ}\text{C}$) unless otherwise specified

Parameter	Symbol	Value	Unit	Test condition
gate trigger current	I_{GT}	≤ 50	mA	T2+G+ $V_D=12\text{V}, I_T=0.1\text{A}$
		≤ 50	mA	T2+G- $V_D=12\text{V}, I_T=0.1\text{A}$
		≤ 50	mA	T2-G- $V_D=12\text{V}, I_T=0.1\text{A}$
		≤ 100	mA	T2-G+ $V_D=12\text{V}, I_T=0.1\text{A}$
gate trigger voltage	V_{GT}	≤ 1.3	V	$V_D=12\text{V}, I_T=0.1\text{A}$
hold current	I_H	≤ 50	mA	$V_D=12\text{V}, I_T=0.1\text{A}$
critical rate of rise off-state voltage	dv/dt	≥ 200	V/ μs	$V_D=67\%V_{DRM}$
on-state voltage	V_{TM}	≤ 1.55	V	$I_T=35\text{A}$
off-state leakage current	I_{DRM}	≤ 3.0	mA	$V_D=V_{DRM}, V_R=V_{RRM}; T_j=125^{\circ}\text{C}$
thermal resistance	$R_{th(j-a)}$	60	$^{\circ}\text{C/W}$	
	$R_{th(j-c)}$	1.7		BTA
	$R_{th(j-c)}$	0.8		BTB

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functional parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damage resulting from such sale(s).

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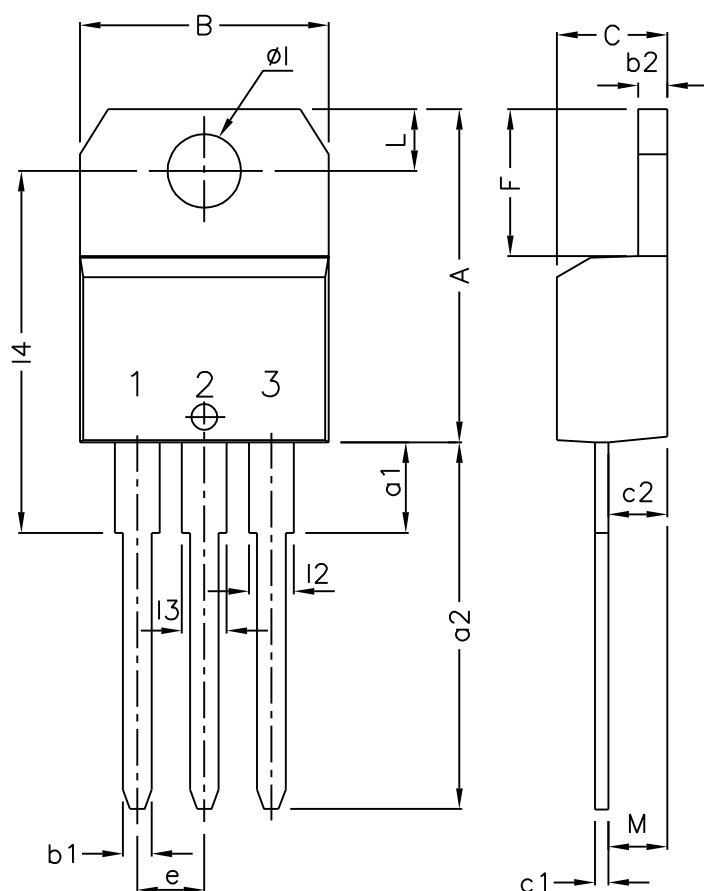
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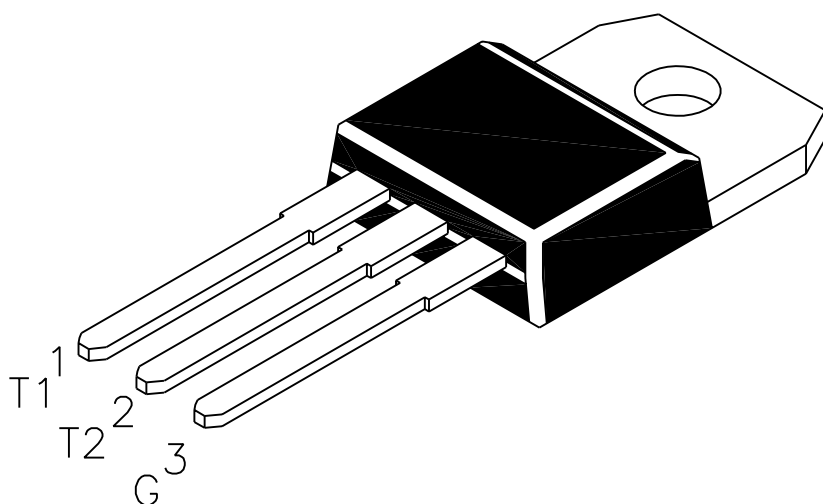
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PACKAGE TO-220 AB



DIM	MIN	TYP.	MAX
A	15.20		15.90
a1		3.75	
a2	13.00		14.00
B	10.00		10.40
b1	0.61		0.88
b2	1.23		1.32
C	4.40		4.60
c1	0.49		0.70
c2	2.40		2.72
e	2.40		2.70
F	6.20		6.60
l	3.75		3.85
l4	15.80	16.40	16.80
L	2.65		2.95
l2	1.14		1.70
l3	1.14		1.70
M		2.60	

ALL DIMENSIONS ARE IN mm



PIN CONFIGURATION:—

1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE